DELKIN DEVICES S330 Series SATA III Industrial 2.5" Solid State Drive Engineering Specification

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Product Overview

- Capacity
 - 16GB up to 256GB
- SATA Interface
 - SATA Revision 3.2
 - SATA 1.5Gbps, 3Gbps, and 6Gbps interface
- Flash Interface
 - Flash type: SLC
- Performance
 - Read: up to 330 MB/s
 - Write: up to 310 MB/s
- Power Consumption^{Note1}
 - Write: < 3,750mW
 - Read: < 3,000mW
 - Idle: < 250mW
- TBW (Terabytes Written) Note2
 - 14,600 for 256GB

- MTBF
 - More than 2,000,000 hours
- Features
 - Static and Dynamic Wear Leveling
 - Bad Block Management
 - TRIM
 - NCQ
 - SMART
 - Over-Provisioning (Option)
 - Firmware Update Capability
 - Temperature Sensor
- Low Power Management
 - DIPM/HIPM Mode
- Temperature Range
 - Operation: -40°C ~ 85°C
 - Storage: -50°C ~ 100°C
- RoHS compliant

Notes:

- 1. Please see "4.2 Power Consumption" for details.
- 2. Please see "TBW (Terabytes Written)" in Chapter 2" for details.

TABLE OF CONTENTS

1.	INTROD	UCTION	6
	1.1. Ge	eneral Description	6
	1.2. Pr	oduct Block Diagram	6
	1.3. Fla	ash Management	6
	1.3.1.	Error Correction Code (ECC)	
	1.3.2.	Wear Leveling	7
	1.3.3.	Bad Block Management	7
	1.3.4.	TRIM	7
	1.3.5.	SMART	7
	1.3.6.	Over-Provisioning	8
	1.3.7.	Firmware Upgrades	8
	1.4. Lo	ow Power Management	8
	1.4.1.	DIPM/HIPM Mode	8
	1.5. Po	ower Loss Protection: Flushing Mechanism	8
	1.6. Ac	dvanced Device Security Features	9
	1.6.1.	Secure Erase	9
	1.6.2.	Write Protect	9
	1.7. SS	SD Lifetime Management	9
	1.7.1.	Terabytes Written (TBW)	9
	1.7.2.	Thermal Monitor	10
	1.8. Ar	n Adaptive Approach to Performance Tuning	10
	1.8.1.	Throughput	10
	1.8.2.	Predict & Fetch	10
2.	PRODUC	CT SPECIFICATIONS	11
3.	ENVIRO	NMENTAL SPECIFICATIONS	13
	3.1. Er	nvironmental Conditions	13
	3.1.1.	Temperature and Humidity	13
	3.1.2.	Shock & Vibration	13
	3.1.3.	Electrostatic Discharge (ESD)	13
	3.2. M	TBF	13
	3.3. Ce	ertification & Compliance	13
4.	ELECTR	ICAL SPECIFICATIONS	14
	4.1. Su	ıpply Voltage	14

	4.2. Power Consumption				
5.	5. INTERFACE				
	5.1.	Pin	Assignment and Descriptions	15	
6.	SUP	PORT	ED COMMANDS	16	
	6.1.	ATA	Command List	16	
	6.2.	lder	ntify Device Data	17	
	6.3.	SMA	ART	21	
	6.3	3.1.	Command Description	21	
	6.3	3.1.1.	I/O Registers	21	
	6.3	3.1.2.	SMART Command Table	22	
	6.3	3.1.3.	SMART Read Attribute	23	
	6.3	3.1.4.	SMART Read Attribute Thresholds	25	
	6.3	3.1.5.	SMART Enable Attribute Auto Save	25	
	6.3	3.1.6.	SMART Disable Attribute Auto Save	26	
	6.3	3.1.7.	SMART Execute Off-Line Immediate	28	
	6.3	3.1.8.	SMART Read Log	29	
	6.3	3.1.9.	SMART Write Log	30	
	6.3	3.1.10	. SMART Enable Operations	31	
	6.3	3.1.11.	. SMART Disable Operations	33	
	6.3	3.1.12	. SMART Return Status	34	
7.	PHY	SICAL	L DIMENSIONS	35	

LIST OF TABLES

Table 4-1 Supply Voltage	14
Table 4-2 Power Consumption	14
Table 5-1 Signal Segment Pin Assignment and Descriptions	15
Table 6-1 ATA Command List	16
Table 6-2 List of Device Identification	17
Table 6-3 List of Device Identification for Each Capacity	20
Table 6-4 Command Block Registers Addressing	21

1. INTRODUCTION

1.1. General Description

Delkin's S330 Series Industrial 2.5" Solid State Drive (SSD) delivers all the advantages of flash disk technology with the performance of the Serial ATA III interface and is fully compliant with the standard 2.5" form factor. Delkin's SSD draws significantly less power compared to traditional hard drives and is also hot swappable. The drive is available in high endurance SLC capacities from 16GB to 256GB and can reach speeds up to 330MB/s read as well as 310MB/s write (measured by CrystalDiskMark v3.0).

1.2. Product Block Diagram

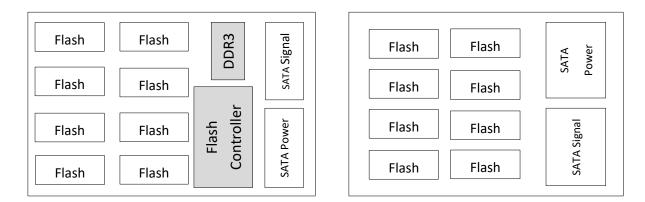


Figure 1-1 SSD Product Block Diagram

1.3. Flash Management

1.3.1. Error Correction Code (ECC)

Flash memory cells will deteriorate with use, which might generate random bit errors in the stored data. Thus, Delkin's Industrial 2.5" SSD applies the BCH ECC algorithm, which can detect and correct errors occur during read process, ensure data been read correctly, as well as protect data from corruption.

1.3.2. Wear Leveling

NAND flash devices can only undergo a limited number of program/erase cycles, and in most cases, the flash media are not used evenly. If some areas are updated more frequently than others, the lifetime of the device would be reduced significantly. Thus, Wear Leveling is applied to extend the lifespan of NAND flash by evenly distributing write and erase cycles across the media.

Delkin utilizes advanced Wear Leveling algorithms, which can efficiently distribute flash usage through the whole flash media area. Moreover, by implementing both dynamic and static Wear Leveling algorithms, the life expectancy of the NAND flash is greatly improved.

1.3.3. Bad Block Management

Bad blocks are blocks that include one or more invalid bits, and their reliability is not guaranteed. Blocks that are identified and marked as bad by the manufacturer are referred to as "Initial Bad Blocks". Bad blocks that are developed during usage of the flash are named "Later Bad Blocks". Delkin implements an efficient bad block management algorithm to detect the factory-produced bad blocks and manages any bad blocks that appear with use. This practice further prevents data being stored into bad blocks and improves data reliability.

1.3.4. TRIM

TRIM is a feature which helps improve the read/write performance and speed of solid-state drives (SSD). Unlike hard disk drives (HDD), SSDs are not able to overwrite existing data, so the available space gradually becomes smaller with each use. With the TRIM command, the operating system can inform the SSD which blocks of data are no longer in use and can be removed permanently. Thus, the SSD will perform an erase action, which prevents unused data from occupying blocks.

1.3.5. SMART

SMART, an acronym for Self-Monitoring, Analysis and Reporting Technology, is an open standard that allows a drive to automatically detect its health and report potential failures. When a failure is recorded by SMART, users can choose to replace the drive to prevent unexpected outage or data loss. Moreover, SMART can inform users of impending failures while there is still time to perform proactive actions, such as copy data to another device.

1.3.6. Over-Provisioning

Over Provisioning refers to the inclusion of extra NAND capacity in a SSD, which is not visible or usable by users. With Over Provisioning, the performance and IOPS (Input/Output Operations per Second) are improved by providing the controller additional space to manage P/E cycles, which enhances the reliability and endurance as well. Moreover, the write amplification of the SSD becomes lower when the controller writes data to the flash. Contact Delkin regarding this customization option.

1.3.7. Firmware Upgrades

Firmware can be considered as a set of instructions on how the device communicates with the host. Firmware can be upgraded when new features are added, compatibility issues are fixed, or read/write performance gets improved, as controlled by the user. Contact Delkin for details.

1.4. Low Power Management

1.4.1. DIPM/HIPM Mode

SATA interfaces contain two low power management states for power saving: Partial and Slumber modes. In Partial mode, the device must resume full operation within 10 microseconds, whereas in Slumber mode, the device has 10 milliseconds to become fully operational. SATA interfaces allow low power modes to be initiated by Host (HIPM, Host Initiated Power Management) or Device (DIPM, Device Initiated Power Management). As for HIPM, Partial or Slumber mode can be invoked directly by the software. For DIPM, the device will send requests to enter Partial or Slumber mode.

1.5. Power Loss Protection: Flushing Mechanism

Power Loss Protection is a mechanism to prevent data loss during unexpected power failures. DRAM is volatile memory and frequently used as temporary cache or buffer between the controller and the NAND flash to improve SSD performance. However, one major concern of the DRAM is that data could be lost in the event of a power failure. Accordingly, the Delkin SATA controller applies the GuaranteedFlush technology, which requests the controller to transfer data to the cache. Only when the data is fully committed to the NAND flash will the controller send acknowledgement (ACK) to the host. Such implementation can prevent false-positive performance and the risk of power cycling issues.

Additionally, it is critical for a controller to shorten the time the in-flight data stays in the cache. Thus, Delkin's controller applies an algorithm to reduce the amount of data residing in the cache to provide better performance. This SmartCacheFlush technology allows incoming data to have only a brief "pit stop" in the cache and then move straight to the NAND flash. If the flash is jammed due to particular file sizes (such as random 4KB data), the cache will be treated as an "organizer", consolidating incoming data into groups before written into the flash to improve write amplification.

In summary, with this advanced Flush Mechanism, Delkin's controller provides the reliability and data protection required by today's applications and hosts.

1.6. Advanced Device Security Features

1.6.1. Secure Erase

Secure Erase is a standard ATA command and will write "0xFF" to all cells, to fully wipe all the data on hard drives and SSDs. When this command is issued, the SSD controller will erase its storage blocks and return to its factory default settings.

1.6.2. Write Protect

When a SSD contains too many bad blocks and data is continuously written in, then the SSD may no longer be usable. Thus, Write Protect is a mechanism to prevent data from being written in and protect the accuracy of data that are already stored in the SSD.

1.7. SSD Lifetime Management

1.7.1. Terabytes Written (TBW)

TBW (Terabytes Written) is a measurement of SSDs' expected lifespan, which represents the amount of data written to the device. To calculate the TBW of a SSD, the following equation is applied:

TBW = [(NAND Endurance) x (SSD Capacity) x (WLE)] / WAF

NAND Endurance: NAND endurance refers to the P/E (Program/Erase) cycle rating of NAND flash, per the manufacturer's specification.

SSD Capacity: The SSD capacity is the specific capacity in total of a SSD.

WLE: Wear Leveling Efficiency (WLE) represents the ratio of the average amount of erases on all the blocks to the erases on any block at maximum.

WAF: Write Amplification Factor (WAF) is a numerical value representing the ratio between

the amount of data that a SSD controller writes to the flash and the amount of data that
the host's flash controller writes. A better WAF, which is near 1, guarantees better

endurance and lower frequency of data written to flash memory.

1.7.2. Thermal Monitor

Thermal monitors are devices for measuring temperature, and can be found in SSDs in order to issue warnings when SSDs go beyond a certain temperature. The higher temperature the thermal monitor detects, the more power the SSD consumes, causing the SSD to age quickly. Hence, the processing speed of a SSD should be under control to prevent temperature from exceeding a certain range. Temperature can be monitored via SMART, as referenced in Section 6.3.

1.8. An Adaptive Approach to Performance Tuning

1.8.1. Throughput

Based on the available space of the disk, Delkin SSD controller will regulate the read/write speed and manage the throughput performance. When significant free space remains, the firmware will continuously perform read/write activity. At this stage, there is still no need to implement garbage collection to allocate and release memory, which will accelerate read/write processing to improve the performance. However, when free space is used up, the controller will slow down the read/write processing, and implement garbage collection to release memory blocks. Hence, read/write performance will become slower.

1.8.2. Predict & Fetch

Normally, when the host tries to read data from the SSD, the SSD will only perform one read action after receiving one command. However, Delkin's controller applies Predict & Fetch to improve the read speed. When the host issues sequential read commands to the SSD, the SSD will automatically expect that the following will also be read commands. Thus, before receiving the next command, flash has already prepared the data. Accordingly, this accelerates the data processing time, and the host does not need to wait as long to receive data.

2. PRODUCT SPECIFICATIONS

Capacity

■ From 16GB up to 256GB

Electrical/Physical Interface

- SATA Interface
 - ♦ Compliant with SATA Revision 3.2
 - ♦ Compatible with SATA 1.5Gbps, 3Gbps and 6Gbps interface
 - ♦ NCQ support up to queue depth = 32
 - Supports power management
 - ♦ Supports expanded register for SATA protocol 48 bit addressing mode

ECC Scheme

■ Capable of correcting up to 120 bits per 2K Bytes of data

Supports SMART and TRIM commands

Performance and Power Consumption

	Performance		Power Consumption	
Capacity	CrystalDiskMark		Read	Write
	Read (MB/s)	Write (MB/s)	(mW)	(mW)
16GB	145	140	1575	1850
32GB	250	230	2000	2500
64GB	330	310	2250	3000
128GB	330	310	2500	3250
256GB	330	310	3000	3750

NOTE:

For more details on Power Consumption, please refer to Chapter 4.2.

Endurance - TBW (Terabytes Written)

Capacity	TBW
16GB	912
32GB	1,825
64GB	3,650
128GB	7,300
256GB	14,600

NOTES:

1. Many factors affect drive endurance / TBW, including flash configuration, SDR configuration, host platform, usage model, write amplification factor, etc. The figures above are estimates and are not guarantees.

Part Numbers

Industrial 2.5" SSD (-40 to 85°C Operating Temperature)

Capacity	Part Number
16GB	DE16TQJA2-35000-D
32GB	DE32TQJA2-35000-D
64GB	DE64TNKA2-35000-D
128GB	DE1HTNJA2-35000-D
256GB	DE2HTNJA2-35000-D

3. ENVIRONMENTAL SPECIFICATIONS

3.1. Environmental Conditions

3.1.1. Temperature and Humidity

- Temperature:
 - ◆ Storage: -40°C to 85°C
 - Operational: -50°C to 100°C
- Humidity:
 - ◆ RH 95% under 55°C (operational)

3.1.2. Shock & Vibration

- Shock Specification
 - ◆ 1500G, 0.5ms duration, 3 axes
- Vibration Specification
 - ◆ 20Hz ~80Hz/1.52mm displacement, 80Hz~2000Hz / 20G Acceleration, 3 axes

3.1.3. Electrostatic Discharge (ESD)

+/- 4KV

3.2. MTBF

MTBF, an acronym for Mean Time Between Failures, is a measure of a device's reliability. Its value represents the average time between a repair and the next failure. The measure is typically in units of hours. The higher the MTBF value, the higher the reliability of the device. The predicted result of Delkin's Industrial 2.5" SSD is more than 2,000,000 hours at 0°C.

3.3. Certification & Compliance

- RoHS
- SATA III (SATA Rev. 3.2)
- Up to ATA/ATAPI-8 (Including S.M.A.R.T)

4. ELECTRICAL SPECIFICATIONS

4.1. Supply Voltage

Table 4-1 Supply Voltage

Parameter	Rating
Operating Voltage	5V ± 5% (Option)
Maximum Ripple	100mV, 0 ~ 30MHz

4.2. Power Consumption

Table 4-2 Power Consumption

Table 4 2 1 Ower Consumption				
Capacity	Read	Write	Idle	
16GB	1575	1850	450	
32GB	2000	2500	450	
64GB	2250	3000	450	
128GB	2500	3250	450	
256GB	3000	3750	450	

Unit: mW

NOTES:

- 1. The average value of power consumption is achieved based on 100% conversion efficiency.
- 2. The measured power voltage is 5V.
- 3. Power Consumption may differ according to flash configuration, SDR configuration, and host platform.

5. INTERFACE

5.1. Pin Assignment and Descriptions

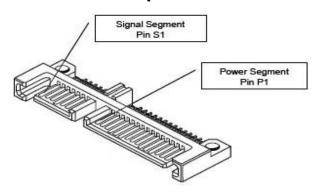


Table 5-1 Signal Segment Pin Assignment and Descriptions

PIN NUMBER	FUNCTION
S1	GND
S2	A+ (DIFFERENTIAL SIGNAL PAIR A)
S3	A- (DIFFERENTIAL SIGNAL PAIR A)
S4	GND
S5	B- (DIFFERENTIAL SIGNAL PAIR B)
S6	B+ (DIFFERENTIAL SIGNAL PAIR B)
S7	GND

Table 0-2 Power Segment Pin Assignment and Descriptions

PIN NUMBER	FUNCTION
P1	NOT USED (3.3V)
P2	NOT USED (3.3V)
P3	DEVSLP
P4	GND
P5	GND
P6	GND
P7	5V PRE-CHARGE
P8	5V
P9	5V
P10	GND
P11	RESERVED
P12	GND
P13	NOT USED (12V PRE-CHARGE)
P14	NOT USED (12V)
P15	NOT USED (12V)

6. SUPPORTED COMMANDS

6.1. ATA Command List

Table 6-1 ATA Command List

Op Code	Description	Op Code	Description
00h	NOP	97h	IDLE
06h	Data Set Management	98h	CHECK POWER MODE
10h-1Fh	10h-1Fh Recalibrate		SLEEP
20h	Read Sectors	B0h	SMART
21h	Read Sectors without Retry	B1h	DEVICE CONFIGURATION
24h	Read Sectors EXT	C4h	Read Multiple
25h	Read DMA EXT	C5h	Write Multiple
27h	Read Native Max Address EXT	C6h	Set Multiple Mode
29h	Read Multiple EXT	C8h	Read DMA
2Fh	Read Log EXT	C9h	Read DMA without Retry
30h	Write Sectors	CAh	Write DMA
31h	Write Sectors without Retry	CBh	Write DMA without Retry
34h	Write Sectors EXT	CEh	Write Multiple FUA EXT
35h	Write DMA EXT	E0h	Standby Immediate
37h	Set Native Max Address EXT	E1h	Idle Immediate
38h CFA WRITE SECTORS WITHOUT ERASE		E2h	Standby
39h Write Multiple EXT		E3h	Idle
3Dh	Write DMA FUA EXT	E4h	Read Buffer
3Fh	Write Long EXT	E5h	Check Power Mode
40h Read Verify Sectors E6h Sleep		Sleep	
41h	Read Verify Sectors without Retry	E7h	Flush Cache
42h	Read Verify Sectors EXT	E8h	Write Buffer
45h	WRITE UNCORRECTABLE EXT	EAh	Flush Cache EXT
60h	Read FPDMA Queued	ECh	Identify Device
61h	Write FPDMA Queued	EFh	Set Features
70h-7Fh	Seek	F1h	Security Set Password
90h	Execute Device Diagnostic	F2h	Security Unlock
91h	Initialize Device Parameters	F3h	Security Erase Prepare
92h	Download Microcode	F4h	Security Erase Unit
93h	DOWNLOAD MICROCODE DMA	F5h	Security Freeze Lock
94h	STANDBY IMMEDIATE	F6h	Security Disable Password
95h	IDLE IMMEDIATE	F8h	Read Native Max Address
96h	STANDBY	F9h	Set Max Address

6.2. Identify Device Data

The following table details the sector data returned by the IDENTIFY DEVICE command.

Table 6-2 List of Device Identification

	F: Fixed		
\Mord	V: Variable	Default Value	Description
Word	X: Both	Default Value	Description
		0040	
0	F	0040h	General configuration bit-significant information
1	X	*1	Obsolete – Number of logical cylinders
2	V	C837h	Specific configuration
3	X	0010h	Obsolete – Number of logical heads (16)
4-5	X	0000000h	Retired
6	X	003Fh	Obsolete – Number of logical sectors per logical track (63)
7-8	V	00000000h	Reserved for assignment by the Compact Flash Association
9	X	0000h	Retired
10-19	F	Varies	Serial number (20 ASCII characters)
20-21	Х	0000h	Retired
22	Х	0000h	Obsolete
23-26	F	Varies	Firmware revision (8 ASCII characters)
27-46	F	Varies	Model number
47	F	8010h	7:0- Maximum number of sectors transferred per interrupt on
			MULTIPLE commands
48	F	4000h	Trusted Computing feature set options(not support)
49	F	2F00h	Capabilities
50	F	4000h	Capabilities
51-52	Х	00000000h	Obsolete
53	F	0007h	Words 88 and 70:64 valid
54	Х	*1	Obsolete – Number of logical cylinders
55	Х	0010h	Obsolete – Number of logical heads (16)
56	X	003Fh	Obsolete – Number of logical sectors per track (63)
57-58	X	*2	Obsolete – Current capacity in sectors
59	F	0110h	Number of sectors transferred per interrupt on MULTIPLE
			commands
60-61	F	*3	Maximum number of sector (28bit LBA mode)
62	X	0000h	Obsolete
63	F	0407h	Multi-word DMA modes supported/selected
64	F	0003h	PIO modes supported
65	F	0078h	Minimum Multiword DMA transfer cycle time per word

	F: Fixed		
Word	V: Variable	Default Value	Description
	X: Both		
66	F	0078h	Manufacturer's recommended Multiword DMA transfer cycle
			time
67	F	0078h	Minimum PIO transfer cycle time without flow control
68	F	0078h	Minimum PIO transfer cycle time with IORDY flow control
69	F	0100h	Additional Supported (support download microcode DMA)
70	F	0000h	Reserved
71-74	F	000000000000000000h	Reserved for the IDENTIFY PACKET DEVICE command
75	F	001Fh	Queue depth
76	F	670eh	Serial SATA capabilities
77	F	0084h	Serial ATA Additional Capabilities
78	F	014Ch	Serial ATA features supported
79	V	0040h	Serial ATA features enabled
80	F	07F8h	Major Version Number
81	F	0000h	Minor Version Number
82	F	346bh	Command set supported
83	F	7d09h	Command set supported
84	F	6063h	Command set/feature supported extension
85	V	3469h	Command set/feature enabled
86	V	bc01h	Command set/feature enabled
87	V	6063h	Command set/feature default
88	V	003Fh	Ultra DMA Modes
89	F	0001h	Time required for security erase unit completion
90	F	001Eh	Time required for Enhanced security erase completion
91	V	0000h	Current advanced power management value
92	V	FFFEh	Master Password Revision Code
93	F	0000h	Hardware reset result. The contents of the bits (12:0) of this
			word can be changed only during the execution of hardware
			reset.
94	V	0000h	Vendor's recommended and actual acoustic management
			value
95	F	0000h	Stream Minimum Request Size
96	V	0000h	Streaming Transfer Time – DMA
97	V	0000h	Streaming Access Latency – DMA and PIO
98-99	F	0000h	Streaming Performance Granularity
100-103	V	*4	Maximum user LBA for 48 bit Address feature set

Word	F: Fixed V: Variable X: Both	Default Value	Description
104	X: Both	0000h	Streaming Transfer Time – PIO
105	F	0008h	Maximum number of 512-byte blocks per DATA SET
	·	0000	MANAGEMENT command
106	F	4000h	Physical sector size/Logical sector size
107	F	0000h	Inter-seek delay for ISO-7779 acoustic testing in
			microseconds
108-111	F	000000000000000000h	Unique ID
112-115	F	000000000000000000h	Reserved
116	V	0000h	Reserved
117-118	F	0000000h	Words per logical Sector
119	F	4014h	Supported settings
120	F	4014h	Command set/Feature Enabled/Supported
121-126	F	0h	Reserved
127	F	0h	Removable Media Status Notification feature set support
128	V	0021h	Security status
129-140	Х	0h	Vendor specific
141	Х	0001h	Vendor specific
142-159	Х	0h	Vendor specific
160	F	0h	Compact Flash Association (CFA) power mode 1
161-167	Х	0h	Reserved for assignment by the CFA
168	F	3h 2.5"	Device Nominal Form Factor
		4h 1.8"	
		5h Less than 1.8"	
169	F	0001h	DATA SET MANAGEMENT command is supported
170-173	F	0h	Additional Product Identifier
174-175		0h	Reserve
176-205	V	0h	Current media serial number
206	F	0h	SCT Command Transport
207-208	F	0h	Reserved
209	F	4000h	Alignment of logical blocks within a physical block
210-211	V	0000h	Write-Read-Verify Sector Count Mode 3 (not supported)
212-213	F	0000h	Write-Read-Verify Sector Count Mode 2 (not supported)
214-216		0000h	NV Cache relate (not supported)
217	F	0001h	Non-rotating media device
218	F	0h	Reserved

Word	F: Fixed V: Variable X: Both	Default Value	Description
219	F	0h	NV Cache relate (not supported)
220	V	0h	Write read verify feature set current mode
221		0h	Reserved
222	F	107Fh	Transport major version number
223	F	0h	Transport minor version number
224-229		0h	reserved
230-233		0h	Extend number of user addressable sectors
234		0001h	Minimum number of 512-byte data blocks per DOWNLOAD MICROCODE command for mode 03h
235		0080h	Maximum number of 512-byte data blocks per DOWNLOAD MICROCODE command for mode 03h
236-254	F	0h	Reserved
255	Х	XXA5h XX is variable	Integrity word (Checksum and Signature)

Table 6-3 List of Device Identification for Each Capacity

Capacity	*1	*2	*3	*4
(GB)	(Word 1/Word 54)	(Word 57 - 58)	(Word 60 - 61)	(Word 100 - 103)
16				
32				
64	3FFFh	FBFC10h	7740AB0h	7740AB0h
128	3FFFh	FBFC10h	EE7C2B0h	EE7C2B0h
256	3FFFh	FBFC10h	FFFFFFh	1DCF32B0h

6.3. SMART

6.3.1. Command Description

6.3.1.1. I/O Registers

Communication to or from device through Data register and 7 Command Block registers (28bits command format), include Feature register, Error register, Sector Count register, Sector Number register, Cylinder Low register, Cylinder High register, Drive Head register, Status register, Command register.

Table 6-4 Command Block Registers Addressing

Offset address	Read	Write	Value Type
0x00	Data	Data	WORD
0x01	Error	Feature	BYTE
0x02	Sector Count	Sector Count	BYTE
0x03	Sector Number	Sector Number	BYTE
	(LBA low current)	(LBA low current)	
0x04	Cylinder Low	Cylinder Low	BYTE
	(LBA Mid current)	(LBA Mid current)	
0x05	Cylinder High	Cylinder High	BYTE
	(LBA High current)	(LBA High current)	
0x06	Drive Head	Drive Head	BYTE
0x07	Status	Command	BYTE

Direction: Input means from Host to Device, Output means from Device to Host

6.3.1.2. SMART Command Table

Vender Command	Feature	Sector	Sector	Cylinder	Cylinder	Drive	Command	
		Count	Number	Low	High	Head		
Smart Read Attribute	0xD0	0x01	XX	0x4F	0xC2	0xA0	0xB0	
Smart Read Attribute	0.404	0,:04	VV	0.45	000	04.0	000	
Thresholds	0xD1	0x01	XX	0x4F	0xC2	0xA0	0xB0	
Smart Enable	0xD2	0νΕ4	VV	0.45	000	0×40	0.400	
Attribute Auto Save	UXDZ	0xF1	XX	0x4F	0xC2	0xA0	0xB0	
Smart Disable	0xD2	0x00	XX	0x4F	0xC2	0xA0	000	
Attribute Auto Save	UXDZ	UXUU	^^	UX4F	UXC2	UXAU	0xB0	
SMART SAVE	0xD3	XX	XX	0x4F	0xC2	0xA0	0xB0	
ATTRIBUTE VALUES	UXD3	^^	^^	UX4F	UXCZ	UXAU	UXDU	
SMART EXECUTE								
OFF-LINE	0xD4	XX	XX	0x4F	0xC2	0xA0	0xB0	
IMMEDIATE								
SMART READ LOG	0xD5	Depends on	XX	0x4F	0xC2	0xA0	0xB0	
	UXDS	Log Address	^^	0,41	0,02	OXAO		
SMART WRITE LOG	0xD6	Depends on	XX	0x4F	0xC2	0xA0	0xB0	
	OXDO	Log Address		0,41	0.02	0240	UXBU	
Smart Enable	0xD8	XX	XX	0x4F	0xC2	0xA0	0xB0	
Operations	UNDO	XX	XX	0,41	0.02	UXAU	OVDO	
Smart Disable	0xD9	XX	XX	0x4F	0xC2	0xA0	0xB0	
Operation	OXD3	<i>/</i> //	,,,,	0,41	0.02		OXDO	
Smart Return Status	0xDA	XX	XX	0x4F	0xC2	0xA0	0xB0	
SMART ENABLE								
AUTOMATIC OFF-	0xDB	XX	XX	0x4F	0xC2	0xA0	0xB0	
LINE								
SMART DISABLE								
AUTOMATIC OFF-	0xDB	XX	XX	0x4F	0xC2	0xA0	0xB0	
LINE								

6.3.1.3. SMART Read Attribute

[Protocol] PIO Data In

[Input]

Register	7	6	5	4	3	2	1	0
Feature				0x	D0			
Sector Count				0×	(01			
Sector Number				N	/A			
(LBA LOW current)								
Cylinder Low				0×	4F			
(LBA MID current)								
Cylinder High				0x	C2			
(LBA HIGH current)								
Drive Head	1	0	1	0	0	0	0	0
Command	0xB0							

[Normal Output]

Register	7	6	5	4	3	2	1	0	
Error	N/A								
Sector Count				N	l/A				
Sector Number				N	I/A				
(LBA LOW current)									
Cylinder Low				N	l/A				
(LBA MID current)									
Cylinder High				N	I/A				
(LBA HIGH current)									
Drive Head	0xE0								
Status		·	·	0>	(50				

[Description]

This command will return 1 sector of SMART Read Attribute information.

Attribute Table

Attribute	Description
ID	
01h	Number of accumulation of uncorrectable error. (Range 0~255)
09h	Power on hours count. (Range 0-4294967295)
0Ch	Drive power cycle count (Number of accumulation of power on/off cycles)
A8h	Sata PHY error count (since last power cycle) this value include all PHY error count, ex data FIS CRC code error, disparity error ,command FIS crc)
AAh	Bad block count.
ADh	Erase count
C0h	Number of unexpected power loss count
C2h	Temperature (See Note 1 for interpretation of temperature data)
DAh	Number of accumulation CRC error (read/write data FIS CRC error)
E7h	SSD life remaining
F1h	Lifetime write from host

Smart attribute actual data

0	1	2	3	4	5	6	7	8	9	10	11	
ID	Flag	flag	value	worse						threshold		
01h	0Bh	00h	64h	64h	0	0	ECC error	0	0	0	0	32h
09h	12h	00h	64h	64h	power o	n hour	0	0	0	0	0	00h
0Ch	12h	00h	64h	64h		power c	n/off cycles		0	0	0	00h
A8h	12h	00h	64h	64h	5	SATA PH	Y error cou	nt	0	0	0	00h
AAh	03h	00h	Note 2	note 2	-	early bad block 0 0		later bad block NO		0	0ah	
ADh	12h	00h	64h	64h		max erase count (MAX 65535)		rase count 65535)	0	0	0	00h
C0h	12h	00h	64h	64h	number	of accide	ntal power l	oss count	0	0	0	00h
C2h	23h	00h	100- Current Temp	100- Highest value		Current Temp (see Note 1)		t Temp lote 1)		t Temp lote 1)	0	1Eh
DAh	0Bh	00h	64h	64h		number of CRC Error		or	0	0	0	32h
E7h	13h	00h	64h	64h	Note 3	0	0	0	0	0	0	00h
F1h	32h	00h	0h	0h		Host writ	e 1GB cour	nt	0	0	0	0

Note 1: Raw data from the drive is a signed 8 bit integer, interpret as follows:

Value 0 – 127: Interpret directly as temperature data, 0 to 127 Degrees C Value 128 – 255: Interpret by subtracting 256, to produce -128 to -1 Degrees C

(100*(A-B))/A, Max = 100, Min = 1, where: Note 2:

A: Maximum Acceptable Number of Bad Block (Plane)

B: Current Number of Maximum Bad Block (Plane)

Note 3: 100 - (average erase count /MAX erase count)*100, where MAX erase count = 60K for SLC, 3K for MLC

6.3.1.4. SMART Read Attribute Thresholds

6.3.1.5. SMART Enable Attribute Auto Save

[Protocol] PIO Non-data

[Input]

Register	7	6	5	4	3	2	1	0
Feature	0xD2							
Sector Count				0X	F1			
Sector Number				N	/A			
(LBA LOW current)								
Cylinder Low				0x	4F			
(LBA MID current)								
Cylinder High				0x0	C2			
(LBA HIGH current)								
Drive Head	1	0	1	0	0 0 0 0			
Command		0xB0						

[Normal Output]

Register	7	6	5	4	3	2	1	0		
Error		N/A								
Sector Count		N/A								
Sector Number				Ν	I/A					
(LBA LOW current)										
Cylinder Low				Ν	I/A					
(LBA MID current)										
Cylinder High				Ν	I/A					
(LBA HIGH										
current)										
Drive Head				0>	Œ0					
Status	0x50									

[Description]

The SMART ENABLE ATTRIBUTE AUTOSAVE command enables the attribute autosave feature of the device. This command may either allow the device, after some vendor specified event, to save the device updated attributes to non-volatile memory or this command may cause the autosave feature to be disabled. The state of the attribute autosave feature,

either enabled or disabled, shall be preserved by the device during all power and reset events. The COUNT field cleared to zero shall cause the device to disable the attribute autosave feature. Disabling this feature does not preclude the device from saving SMART data to non-volatile memory during some other normal operation (e.g., during a power-on or power-off sequence or during an error recovery sequence).

The COUNT field set to F1h shall cause the device to enable the attribute autosave feature. If the COUNT field is not set to 00h or F1h, then the actions taken by a device are vendor specific. If the device receives a command while processing the autosave routine the device shall begin processing the command within 2 s.

6.3.1.6. SMART Disable Attribute Auto Save

[Protocol] PIO Non-data

Register	7	6	5	4	3	2	1	0
Feature	0xD2							
Sector Count	0x00							
Sector Number		N/A						
(LBA LOW								
current)								
Cylinder Low				0x	4F			
(LBA MID								
current)								
Cylinder High				0x	C2			
(LBA HIGH								
current)								
Drive Head	1	1 0 1 0 0 0 0 0						
Command				0x	В0			

Register	7	6	5	4	3	2	1	0
Error				Ν	I/A			
Sector Count				Ν	I/A			
Sector Number				Ν	I/A			
(LBA LOW current)								
Cylinder Low				Ν	I/A			
(LBA MID current)								
Cylinder High				Ν	I/A			
(LBA HIGH current)								
Drive Head		0xE0						
Status				0)	k 50			

[Description]

The SMART DISABLE ATTRIBUTE AUTOSAVE command disables the attribute autosave feature of the device. This command may either allow the device, after some vendor specified event, to save the device updated attributes to non-volatile memory or this command may cause the autosave feature to be disabled. The state of the attribute autosave feature, either enabled or disabled, shall be preserved by the device during all power and reset events. The COUNT field cleared to zero shall cause the device to disable the attribute autosave feature. Disabling this feature does not preclude the device from saving SMART data to non-volatile memory during some other normal operation (e.g., during a power-on or power-off sequence or during an error recovery sequence).

The COUNT field set to F1h shall cause the device to enable the attribute autosave feature. If the COUNT field is not set to 00h or F1h, then the actions taken by a device are vendor specific.

If the device receives a command while processing the autosave routine the device shall begin processing the command within 2 s.

6.3.1.7. SMART Execute Off-Line Immediate

[Protocol] PIO Non-data

[Input]

Register	7	6	5	4	3	2	1	0	
Feature		0xD4							
Sector Count		0x00							
Sector Number				subcor	nmand				
(LBA LOW current)									
Cylinder Low				0x	4F				
(LBA MID current)									
Cylinder High				0x0	C2				
(LBA HIGH current)									
Drive Head	1 0 1 0 0 0 0 0								
Command		0xB0							

[Normal Output]

Register	7	6	5	4	3	2	1	0
Error				N	I/A			
Sector Count				N	I/A			
Sector Number				N	I/A			
(LBA LOW current)								
Cylinder Low				N	I/A			
(LBA MID current)								
Cylinder High				N	I/A			
(LBA HIGH current)								
Drive Head		0xE0						
Status			·	0>	< 50		·	

[Description]

The SMART EXECUTE OFF-LINE IMMEDIATE command causes the device to initiate the optional set of activities that collect SMART data in an off-line mode and then preserve this data across power and reset events, or process a vendor specific self-diagnostic test routine in either captive or off-line mode.

Value	Description of subcommand to be processed
00h	Execute SMART off-line routine in off-line mode
01h	Execute SMART Short self-test routine in off-line mode
02h	Execute SMART Extended self-test routine in off-line mode
03h (not supported)	Execute SMART Conveyance self-test routine in off-line mode
04h	Execute SMART Selective self-test routine in off-line mode
05h-3Fh	Reserved
40h-7Eh	Vendor specific
7Fh	Abort off-line mode self-test routine
80h	Reserved
81h	Execute SMART Short self-test routine in captive mode
82h	Execute SMART Extended self-test routine in captive mode
83h (not supported)	Execute SMART Conveyance self-test routine in captive mode
84h	Execute SMART Selective self-test routine in captive mode
85h-8Fh	Reserved
90h-FFh	Vendor specific

6.3.1.8. SMART Read Log

[Protocol] PO Data-In

Register	7	6	5	4	3	2	1	0
Feature		0xD5						
Sector Count			Dep	end on I	Log Addr	ess		
Sector Number				Log Ad	ddress			
(LBA LOW current)								
Cylinder Low				0x	4F			
(LBA MID current)								
Cylinder High				0x	C2			
(LBA HIGH current)								
Drive Head	1	1 0 1 0 0 0 0						
Command				0x	B0			

Register	7	6	5	4	3	2	1	0
Error				N	I/A			
Sector Count				N	I/A			
Sector Number				N	I/A			
(LBA LOW current)								
Cylinder Low				N	I/A			
(LBA MID current)								
Cylinder High				N	I/A			
(LBA HIGH current)								
Drive Head		0xE0						
Status				0>	< 50			

[Description]

The SMART READ LOG command returns the specified log to the host.

6.3.1.9. SMART Write Log

[Protocol] PO Data-Out

Register	7	6	5	4	3	2	1	0	
Feature		0xD6							
Sector Count		Depend on Log Address							
Sector Number				Log A	ddress				
(LBA LOW current)									
Cylinder Low				0x	4F				
(LBA MID current)									
Cylinder High				0x	C2				
(LBA HIGH current)									
Drive Head	1	1 0 1 0 0 0 0 0							
Command		0xB0							

Register	7	6	5	4	3	2	1	0
Error				N	I/A			
Sector Count				N	I/A			
Sector Number				N	I/A			
(LBA LOW current)								
Cylinder Low				N	I/A			
(LBA MID current)								
Cylinder High				N	I/A			
(LBA HIGH current)								
Drive Head		0xE0						
Status				0>	< 50			

[Description]

The SMART WRITE LOG command returns the specified log to the host.

6.3.1.10. SMART Enable Operations

[Protocol] PIO Non-data

Register	7	6	5	4	3	2	1	0	
Feature		0xD8							
Sector Count				N	/A				
Sector Number				N	/A				
(LBA LOW current)									
Cylinder Low				0x	4F				
(LBA MID current)									
Cylinder High				0x	C2				
(LBA HIGH current)									
Drive Head	1	1 0 1 0 0 0 0 0							
Command				0x	В0				

Register	7	6	5	4	3	2	1	0
Error				N	I/A			
Sector Count				١	I/A			
Sector Number		N/A						
(LBA LOW current)								
Cylinder Low				N	I/A			
(LBA MID current)								
Cylinder High				N	I/A			
(LBA HIGH current)								
Drive Head		0xE0						
Status				0:	x50			

[Description]

The SMART ENABLE OPERATIONS command enables access to all available SMART capabilities within the device. The state of SMART, either enabled or disabled, shall be preserved by the device during all power and reset events. Once enabled, the receipt of subsequent SMART ENABLE OPERATIONS commands shall not affect any SMART data or functions.

6.3.1.11. SMART Disable Operations

[Protocol] PIO Non-data

[Input]

Register	7	6	5	4	3	2	1	0
Feature		0xD9						
Sector Count				N	/A			
Sector Number				N	/A			
(LBA LOW current)								
Cylinder Low				0x	4F			
(LBA MID current)								
Cylinder High				0x	C2			
(LBA HIGH current)								
Drive Head	1 0 1 0 0 0 0 0							0
Command	0xB0							

[Normal Output]

Register	7	6	5	4	3	2	1	0
Error				Ν	I/A			
Sector Count				Ν	I/A			
Sector Number				Ν	I/A			
(LBA LOW current)								
Cylinder Low				Ν	I/A			
(LBA MID current)								
Cylinder High				Ν	I/A			
(LBA HIGH current)								
Drive Head				0>	Œ0			
Status	0x50							

[Description]

The SMART DISABLE OPERATIONS command shall disable all SMART operations. After completion of this command without error the device shall report command aborted for all other SMART commands (e.g., SMART DISABLE OPERATIONS commands), except for the SMART ENABLE OPERATIONS command and the SCT Command Transport commands, which shall be processed as defined. The state of SMART (i.e., enabled or disabled) shall be preserved by the device during all power-on reset events.

6.3.1.12. SMART Return Status

[Protocol] PIO Non-data

[Input]

Register	7	6	5	4	3	2	1	0
Feature	0xDA							
Sector Count		N/A						
Sector Number	N/A							
(LBA LOW current)								
Cylinder Low	0x4F							
(LBA MID current)								
Cylinder High	0xC2							
(LBA HIGH current)								
Drive Head	1	0	1	0	0	0	0	0
Command	0xB0							

[Normal Output]

Register	7	6	5	4	3	2	1	0
Error		N/A						
Sector Count		N/A						
Sector Number				N	/A			
(LBA LOW current)								
Cylinder Low				N	/A			
(LBA MID current)								
Cylinder High				N	/A			
(LBA HIGH current)								
Drive Head				0x	E0			
Status	0x50							

[Description]

The SMART RETURN STATUS command causes the device to communicate the reliability status of the device to the host.

Status Return:

If Current Reserved Block > 3, return 0x4F, 0xC2

If Current Reserved Block <= 3, detected a threshold exceeded condition, return 0xF4, 0x2C

7. PHYSICAL DIMENSIONS

Dimension	Measurement
Height	9.20 mm ±0.15 (0.36")
Width	69.75 mm +0.25/-0.15 (2.75")
Length	99.70 mm ±0.25 (3.93")

